NSN 5961-01-311-1353

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-311-1353 **Inclosure Material:** Glass **Overall Length:** 0.205 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.107 inches **Function For Which Designed:** Zener diode Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 7.0 regulator voltage and 7.9 regulator voltage **Current Rating Per Characteristic:** 35.00 milliamperes all primaries horsepower metric and 140.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 1.3 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 30881-1002113 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**